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**ON Semiconductor®** 

# FDMS9408-F085 N-Channel PowerTrench<sup>®</sup> MOSFET

## **40 V, 80 A, 1.8 m**Ω

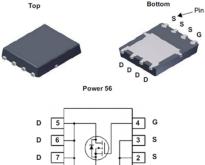
#### Features

- Typical  $R_{DS(on)}$  = 1.5 m $\Omega$  at  $V_{GS}$  = 10V,  $I_D$  = 80 A
- Typical Q<sub>g(tot)</sub> = 68 nC at V<sub>GS</sub> = 10V, I<sub>D</sub> = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

#### Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems





FDMS9408-F085 N-Channel PowerTrench<sup>®</sup> MOSFET

5 6 7 7 8 1 5 4 6 3 5 2 5 8 1 5

D

**MOSFET Maximum Ratings** T<sub>J</sub> = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-to-Source Voltage		40	V
V <sub>GS</sub>	Gate-to-Source Voltage		±20	V
-	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> =25°C	80	
D	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure 4	Α
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	143	mJ
<b>D</b>	Power Dissipation		214	W
P <sub>D</sub>	Derate Above 25°C		1.43	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.7	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W

#### Notes:

1: Current is limited by bondwire configuration.

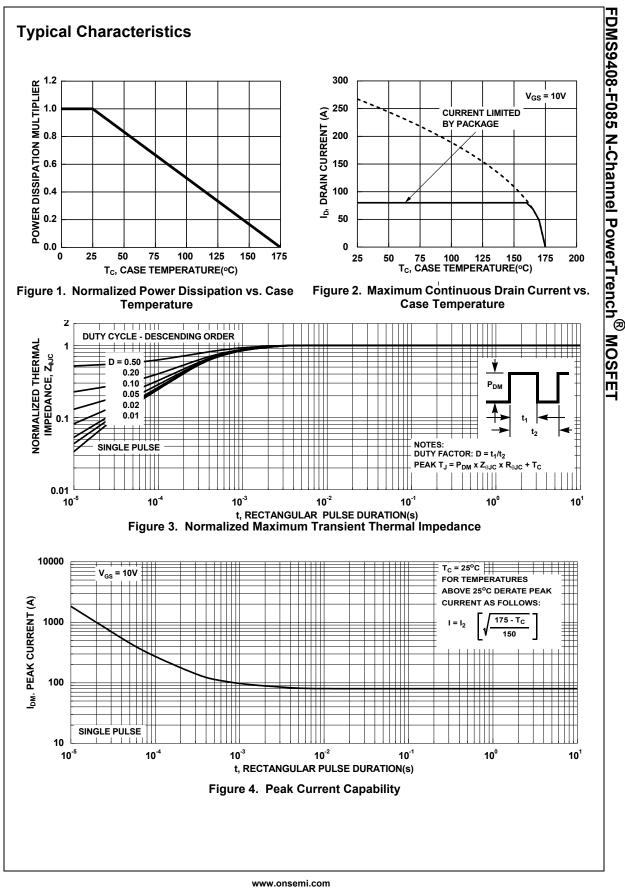
2: Starting  $T_J = 25^{\circ}$ C, L = 70uH,  $I_{AS} = 64$ A,  $V_{DD} = 40$ V during inductor charging and  $V_{DD} = 0$ V during time in avalanche.

3: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>0JC</sub> is guaranteed by design, while R<sub>0JA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

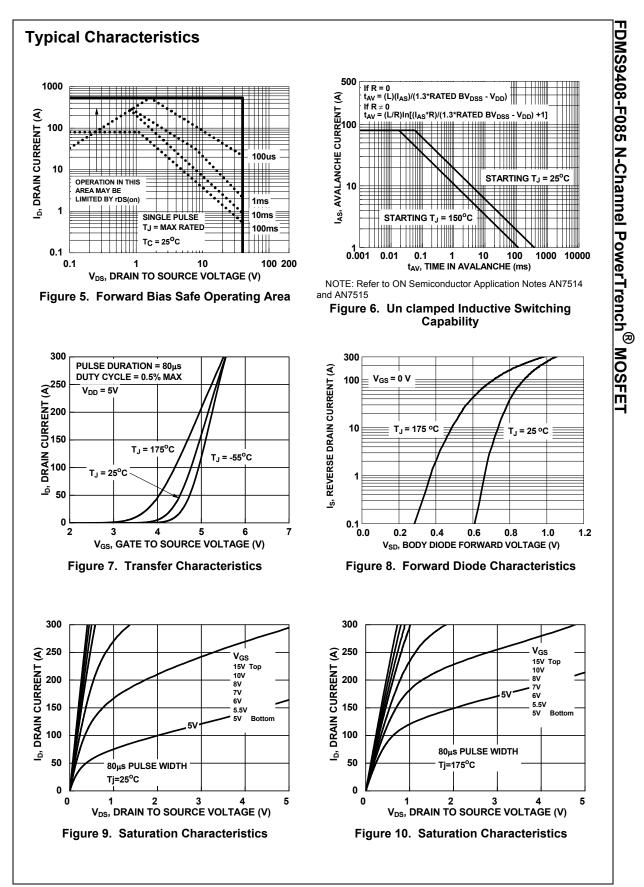
### Package Marking and Ordering Information

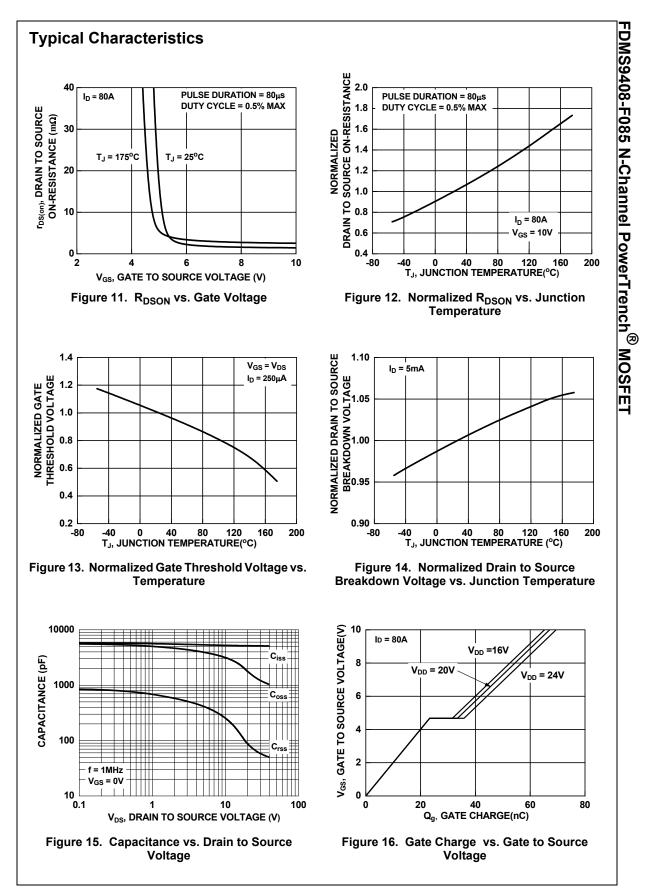
Dev	vice Marking	Device	Package	Reel Size	Tape Width	Quantity
F	DMS9408	FDMS9408-F085	Power56	13"	12mm	3000units

Symbol	Parameter	Tes	t Conditions	Min.	Тур.	Max.	Units
Off Cha	racteristics						
B <sub>VDSS</sub>	Drain-to-Source Breakdown Voltage	I <sub>D</sub> = 250μA, 1	V <sub>GS</sub> =0V	40	-	-	V
I <sub>DSS</sub>	Drain-to-Source Leakage Current	V <sub>DS</sub> =40V,		-	-	1	μA mA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> ,		2.0	3.0	4.0	V
R <sub>DS(on)</sub>	Drain to Source On Resistance	I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V	$T_J = 25^{\circ}C$ $T_J = 175^{\circ}C$ (Note 4)	-	1.5 2.5	1.8 3.0	mΩ mΩ
Dynami	ic Characteristics						
C <sub>iss</sub>	Input Capacitance		( <u>0)</u> (	-	5150	-	pF
C <sub>oss</sub>	Output Capacitance	− V <sub>DS</sub> = 20V, V f = 1MHz	/ <sub>GS</sub> = 0V,	-	1770	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1MHz		-	89	-	pF
R <sub>g</sub>	Gate Resistance	f = 1MHz		-	2.8	-	Ω
Q <sub>g(ToT)</sub>	Total Gate Charge	V <sub>GS</sub> = 0 to 1	0V V <sub>DD</sub> = 32V	-	68	92	nC
Q <sub>g(th)</sub>	Threshold Gate Charge	$V_{GS} = 0$ to 2		-	9.3	14	nC
Q <sub>gs</sub>	Gate-to-Source Gate Charge			-	22	-	nC
	Gate-to-Drain "Miller" Charge		-	-	12	-	nC
Q <sub>gd</sub>							
Switchi	ng Characteristics			-	-	51	ns
Switchi t <sub>on</sub> t <sub>d(on)</sub>	Turn-On Time Turn-On Delay	 	- 904	-	19	-	ns
Switchi t <sub>on</sub> t <sub>d(on)</sub> t <sub>r</sub>	Turn-On Time Turn-On Delay Rise Time	V <sub>DD</sub> = 20V, V <sub>CS</sub> = 10V.		-	19 20	-	ns ns
Switchi t <sub>on</sub> t <sub>d(on)</sub> t <sub>r</sub> t <sub>d(off)</sub>	Turn-On Time Turn-On Delay Rise Time Turn-Off Delay	V <sub>DD</sub> = 20V, V <sub>GS</sub> = 10V,		-	19 20 41	- - -	ns ns ns
Switchi $t_{on}$ $t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$	Turn-On Time Turn-On Delay Rise Time Turn-Off Delay Fall Time			-	19 20	-	ns ns ns ns
t <sub>on</sub> t <sub>d(on)</sub> t <sub>r</sub> t <sub>d(off)</sub> t <sub>f</sub> t <sub>off</sub>	Turn-On Time Turn-On Delay Rise Time Turn-Off Delay				19 20 41 19	- - -	ns ns ns
Switchi $t_{on}$ $t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$ $t_{off}$ Drain-S	Turn-On Time   Turn-On Delay   Rise Time   Turn-Off Delay   Fall Time   Turn-Off Time		R <sub>GEN</sub> = 6Ω		19 20 41 19	-	ns ns ns ns
Switchi $t_{on}$ $t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$ $t_{off}$ Drain-S	Turn-On Time   Turn-On Delay   Rise Time   Turn-Off Delay   Fall Time   Turn-Off Time	V <sub>GS</sub> = 10V,	R <sub>GEN</sub> = 6Ω		19 20 41 19	- - - 79	ns ns ns ns
Switchi $t_{on}$ $t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$ $t_{off}$	Turn-On Time   Turn-On Delay   Rise Time   Turn-Off Delay   Fall Time   Turn-Off Time	V <sub>GS</sub> = 10V,	R <sub>GEN</sub> = 6Ω	- - - - -	19 20 41 19 -	- - - 79 1.25	ns ns ns ns V



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